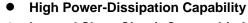
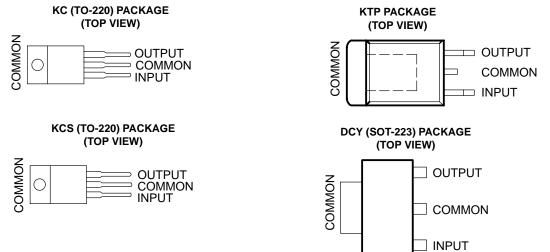
- 3-Terminal Regulators
- Output Current up to 500 mA
- **No External Components**
- **Internal Thermal-Overload Protection**



- **Internal Short-Circuit Current Limiting**
- **Output Transistor Safe-Area Compensation**



description/ordering information

This series of fixed-voltage integrated-circuit voltage regulators is designed for a wide range of applications. These applications include on-card regulation for elimination of noise and distribution problems associated with single-point regulation. Each of these regulators can deliver up to 500 mA of output current. The internal current-limiting and thermal-shutdown features of these regulators essentially make them immune to overload. In addition to use as fixed-voltage regulators, these devices can be used with external components to obtain adjustable output voltages and currents, and also as the power-pass element in precision regulators.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



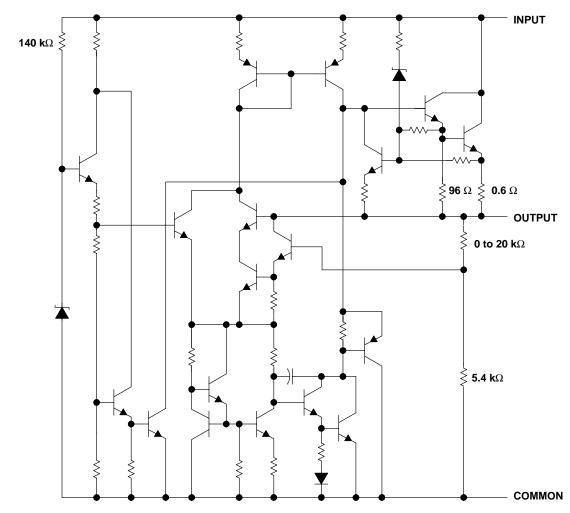
ORDERING INFORMATION

TJ	V _O (NOM) (V)	PACKAGE [†]		ORDERABLE PART NUMBER	TOP-SIDE MARKING
		Power Flex (KTP)	Reel of 3000	μΑ78M33CKTPR	UA78M33C
	3.3	SOT-223 (DCY)	Tube of 80	μΑ78M33CDCY	СЗ
	3.3	301-223 (DC1)	Reel of 2500	μΑ78M33CDCYR	
		TO-220 (KC)	Tube of 50	μΑ78М33СКС	UA78M33C
		Power Flex (KTP)	Reel of 3000	μΑ78M05CKTPR	UA78M05C
		COT 222 (DCV)	Tube of 80	μΑ78M05CDCY	C5
	5	SOT-223 (DCY)	Reel of 2500	μΑ78M05CDCYR	
		TO-220 (KC)	Tube of 50	μΑ78M05CKC	LIAZOMOEC
0°C to 125°C		TO-220 (KCS, short shoulder)	Tube of 20	μΑ78M05CKCS	UA78M05C
	6	Power Flex (KTP)	Reel of 3000	μΑ78M06CKTPR	UA78M06C
		Power Flex (KTP)	Reel of 3000	μΑ78M08CKTPR	UA78M08C
	8	COT 222 (DCV)	Tube of 80	μΑ78M08CDCY	C8
	٥	SOT-223 (DCY)	Reel of 2500	μΑ78M08CDCYR	7 %
		TO-220 (KC)	Tube of 50	μΑ78M08CKC	UA78M08C
	9	Power Flex (KTP)	Reel of 3000	μΑ78M09CKTPR	UA78M09C
	40	Power Flex (KTP)	Reel of 3000	μΑ78M12CKTPR	UA78M12C
	12	TO-220 (KC)	Tube of 50	μΑ78M12CKC	UA78M12C

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



schematic



Resistor values shown are nominal.

absolute maximum ratings over virtual junction temperature range (unless otherwise noted)†

Input voltage, V _I		
Package thermal impedance, θ _{JA} (see Notes 1 and 2):	DCY package	49°C/W
•	KC package	25°C/W
	KCS package	25°C/W
	KTP package	
Lead temperature 1,6 mm (1/16 inch) from case for 10	seconds	260°C
Virtual junction temperature range, T _J		0°C to 150°C
Storage temperature range, T _{stg}		–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The package thermal impedance is calculated in accordance with JESD 51-5.

recommended operating conditions

			MIN	MAX	UNIT
		μΑ78Μ33	5.3	25	
		μA78M335.325μA78M05725μA78M06825μA78M0810.525μA78M0911.526μA78M1012.528μA78M1214.530μA78M1517.530			
µА78М08 10.5	25				
.	Input voltage	25	V		
VI	input voitage	μΑ78Μ09	11.5	26	V
		μΑ78Μ10	12.5	28	
		μΑ78Μ12	14.5	30	
		μΑ78Μ15	17.5	30	
lo	Output current			500	mA
TJ	Operating virtual junction temperature		0	125	°C



NOTES: 1. Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Selecting the maximum of 150°C can affect reliability.

electrical characteristics at specified virtual junction temperature, $V_I = 8 \text{ V}$, $I_O = 350 \text{ mA}$, $T_J = 25^{\circ}\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS†			μ Α78M33C		
PARAMETER	TES	GI CONDITIONS!	MIN	TYP	MAX	UNIT
Output wells as t	$I_{O} = 5 \text{ mA to } 350 \text{ mA},$		3.2	3.3	3.4	V
Output voltage‡	V _I = 8 V to 20 V	T _J = 0°C to 125°C	3.1	3.3	3.5	V
Innut valtage regulation	I- 200 mA	V _I = 5.3 V to 25 V		9	100	mV
Input voltage regulation	I _O = 200 mA	V _I = 8 V to 25 V		3	50	IIIV
Dinnle rejection	V _I = 8 V to 18 V,	$I_{O} = 100 \text{ mA}, T_{J} = 0^{\circ}\text{C to } 125^{\circ}\text{C}$	62			dB
Ripple rejection	f = 120 Hz	I _O = 300 mA	62	80		иь
Output voltage regulation	V _I = 8 V,	I _O = 5 mA to 500 mA		20	100	mV
Temperature coefficient of output voltage	$I_O = 5 \text{ mA},$	$T_J = 0$ °C to 125°C		-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz			40	200	μV
Dropout voltage				2		V
Bias current				4.5	6	mA
Dies surrent change	$I_O = 200 \text{ mA},$	$V_I = 8 \text{ V to } 25 \text{ V}, T_J = 0^{\circ}\text{C to } 125^{\circ}\text{C}$			0.8	A
Bias current change	$I_O = 5$ mA to 350 mA,	$T_J = 0$ °C to 125°C			0.5	mA
Short-circuit output current	V _I = 35 V			300		mA
Peak output current				700		mA

[†] All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

electrical characteristics at specified virtual junction temperature, $V_I = 10 \text{ V}$, $I_O = 350 \text{ mA}$, $T_J = 25^{\circ}\text{C}$ (unless otherwise noted)

PARAMETER		ST CONDITIONS†	μ Δ	78M050	;	UNIT
PARAMETER	TES	MIN	TYP	MAX	UNIT	
Output walks as	$I_0 = 5 \text{ mA to } 350 \text{ mA},$		4.8	5	5.2	V
Output voltage	$V_{I} = 7 \text{ V to } 20 \text{ V}$	$T_J = 0$ °C to 125°C	4.75		5.25	V
Input valtage regulation	I _O = 200 mA	V _I = 7 V to 25 V		3	100	mV
Input voltage regulation	IO = 200 IIIA	V _I = 8 V to 25 V		1	50	IIIV
Pipple rejection	$V_{I} = 8 \text{ V to } 18 \text{ V},$	$I_O = 100 \text{ mA}, T_J = 0^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}$	62			dB
Ripple rejection	f = 120 Hz	I _O = 300 mA	62	80		uБ
Output voltage regulation	$I_O = 5 \text{ mA to } 500 \text{ mA}$			20	100	mV
Output voltage regulation	$I_O = 5 \text{ mA to } 200 \text{ mA}$			10	50	IIIV
Temperature coefficient of output voltage	$I_O = 5 \text{ mA},$	$T_J = 0$ °C to 125°C		-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz			40	200	μV
Dropout voltage				2		V
Bias current				4.5	6	mA
Dies surrent change	I _O = 200 mA,	$V_{I} = 8 \text{ V to } 25 \text{ V}, T_{J} = 0^{\circ}\text{C to } 125^{\circ}\text{C}$			0.8	mA
Bias current change	$I_0 = 5 \text{ mA to } 350 \text{ mA},$	$T_J = 0$ °C to 125°C			0.5	IIIA
Short-circuit output current	V _I = 35 V			300		mA
Peak output current				0.7		Α

[†] All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.



[‡] This specification applies only for dc power dissipation permitted by absolute maximum ratings.

electrical characteristics at specified virtual junction temperature, $V_I = 11 \text{ V}$, $I_O = 350 \text{ mA}$, $T_J = 25^{\circ}\text{C}$ (unless otherwise noted)

PARAMETER				μ Α	78M060	С	UNIT
PARAMETER	TEST CONDITIONS [†]				TYP	MAX	UNII
Output voltage	$I_{O} = 5 \text{ mA to } 350 \text{ mA},$	V _I = 8 V to 21 V		5.75	6	6.25	V
Output voltage	O = 3 IIIA to 330 IIIA,	V = 0 V 10 21 V	$T_J = 0$ °C to 125°C	5.7		6.3	V
Input voltage regulation	I _O = 200 mA	V _I = 8 V to 25 V			5	100	mV
input voltage regulation	10 = 200 IIIA	$V_{I} = 9 \text{ V to } 25 \text{ V}$			1.5	50	1117
Ripple rejection	V _I = 9 V to 19 V,	f = 120 Hz	$I_O = 100 \text{ mA},$ $T_J = 0^{\circ}\text{C to } 125^{\circ}\text{C}$	59			dB
11			I _O = 300 mA	59	80		
Output voltage regulation	$I_O = 5 \text{ mA to } 500 \text{ mA}$				20	120	mV
Output voltage regulation	$I_O = 5$ mA to 200 mA				10	60	IIIV
Temperature coefficient of output voltage	I _O = 5 mA,	$T_J = 0$ °C to 125°C			-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				45		μV
Dropout voltage					2		V
Bias current					4.5	6	mA
Dies surrent change	$V_{I} = 9 V \text{ to } 25 V,$	$I_O = 200 \text{ mA},$	$T_J = 0$ °C to 125°C			0.8	mA
Bias current change	$I_0 = 5 \text{ mA to } 350 \text{ mA},$	T _J = 0°C to 125°C				0.5	IIIA
Short-circuit output current	V _I = 35 V				270		mA
Peak output current					0.7		Α

TAll characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

electrical characteristics at specified virtual junction temperature, V_I = 14 V, I_O = 350 mA, T_J = 25°C (unless otherwise noted)

PARAMETER	TEST COMPITIONS			μ Α	78M080)	UNIT
PARAMETER		TEST CONDITIONS†		MIN	TYP	MAX	ONIT
	V 10 5 V to 22 V	l = - Ε m Λ to 3Ε0 m Λ		7.7	8	8.3	V
Output voltage	$V_{I} = 10.5 \text{ V to } 23 \text{ V},$	$I_O = 5 \text{ mA to } 350 \text{ mA}$	$T_J = 0$ °C to 125°C	7.6		8.4	V
Input voltage regulation	lo - 200 mA	V _I = 10.5 V to 25 V			6	100	mV
Input voltage regulation	I _O = 200 mA	V _I = 11 V to 25 V			2	50	IIIV
Pinnle rejection	V _I = 11.5 V to 21.5 V,	$I_0 = 100 \text{ mA},$	$T_J = 0$ °C to 125°C	56			dB
Ripple rejection	f = 120 Hz	IO = 300 mA		56	80		иь
Output voltage regulation	$I_O = 5 \text{ mA to } 500 \text{ mA}$				25	160	mV
Output voltage regulation	$I_O = 5 \text{ mA to } 200 \text{ mA}$				10	80	IIIV
Temperature coefficient of output voltage	I _O = 5 mA,	T _J = 0°C to 125°C			-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				52		μV
Dropout voltage					2		V
Bias current					4.6	6	mA
Ding gurrant change	$V_I = 10.5 \text{ V to } 25 \text{ V},$	I _O = 200 mA,	$T_J = 0$ °C to 125°C			0.8	A
Bias current change	$I_{O} = 5 \text{ mA to } 350 \text{ mA},$	T _J = 0°C to 125°C				0.5	mA
Short-circuit output current	V _I = 35 V				250		mA
Peak output current			_		0.7		Α

[†] All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.



electrical characteristics at specified virtual junction temperature, $V_I = 16 \text{ V}$, $I_O = 350 \text{ mA}$, $T_J = 25^{\circ}\text{C}$ (unless otherwise noted)

PARAMETER				μ Α	78M090		UNIT
PARAMETER	TEST CONDITIONS [†]				TYP	MAX	ONIT
Outrout walks as	V _I = 11.5 V to 24 V,	I _O = 5 mA to 350 mA		8.6	9	9.4	V
Output voltage	V = 11.5 V to 24 V,	10 = 3 IIIA to 330 IIIA	$T_J = 0$ °C to 125°C	8.5		9.5	V
Input voltage regulation	I _O = 200 mA	V _I = 11.5 V to 26 V			6	100	mV
input voltage regulation	10 = 200 IIIA	V _I = 12 V to 26 V			2	50	IIIV
Ripple rejection	V _I = 13 V to 23 V,	I _O = 100 mA,	$T_J = 0$ °C to 125°C	56			dB
Rippie rejection	f = 120 Hz	I _O = 300 mA		56	80		иь
Output voltage regulation	I _O = 5 mA to 500 mA				25	180	mV
Output voltage regulation	$I_O = 5 \text{ mA to } 200 \text{ mA}$				10	90	IIIV
Temperature coefficient of output voltage	I _O = 5 mA,	$T_J = 0$ °C to 125°C			-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				58		μV
Dropout voltage					2		V
Bias current					4.6	6	mA
Dies surrent shangs	V _I = 11.5 V to 26 V,	I _O = 200 mA,	$T_J = 0$ °C to 125°C			0.8	mA
Bias current change	$I_0 = 5 \text{ mA to } 350 \text{ mA},$	T _J = 0°C to 125°C				0.5	mA
Short-circuit output current	V _I = 35 V				250		mA
Peak output current					0.7		Α

[†] All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

electrical characteristics at specified virtual junction temperature, $V_I = 17 \text{ V}$, $I_O = 350 \text{ mA}$, $T_J = 25^{\circ}\text{C}$ (unless otherwise noted)

DADAMETED		TEST CONDITIONS [†]			78M100	2	UNIT
PARAMETER					TYP	MAX	
O to t allows	\/. = 12.5 \/ to 25 \/	l = - Ε m Λ to 3Ε0 m Λ		9.6	10	10.4	V
Output voltage	$V_{I} = 12.5 \text{ V to } 25 \text{ V},$	$I_O = 5 \text{ mA to } 350 \text{ mA}$	$T_J = 0$ °C to 125°C	9.5		10.5	V
Input voltage regulation	lo - 200 mA	V _I = 12.5 V to 28 V			7	100	mV
Input voltage regulation	I _O = 200 mA	V _I = 14 V to 28 V			2	50	IIIV
Dinale rejection	V _I = 15 V to 25 V,	I _O = 100 mA,	$T_J = 0^{\circ}C$ to $125^{\circ}C$	59			dB
Ripple rejection	f = 120 Hz	I _O = 300 mA		55	80		иь
Output voltage regulation	$I_O = 5 \text{ mA to } 500 \text{ mA}$				25	200	mV
Output voltage regulation	$I_O = 5 \text{ mA to } 200 \text{ mA}$				10	100	IIIV
Temperature coefficient of output voltage	I _O = 5 mA,	$T_J = 0$ °C to 125°C			-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				64		μV
Dropout voltage					2		V
Bias current					4.7	6	mA
Dies surrent change	V _I = 12.5 V to 28 V,	I _O = 200 mA,	T _J = 0°C to 125°C			0.8	A
Bias current change	$I_O = 5 \text{ mA to } 350 \text{ mA},$	T _J = 0°C to 125°C				0.5	mA
Short-circuit output current	V _I = 35 V				245		mA
Peak output current					0.7		Α

[†] All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.



electrical characteristics at specified virtual junction temperature, $V_I = 19 \text{ V}$, $I_O = 350 \text{ mA}$, $T_J = 25^{\circ}\text{C}$ (unless otherwise noted)

PARAMETER				μ Α	78M120	5	UNIT
PARAMETER		TEST CONDITIONS†	_	MIN	TYP	MAX	UNIT
Outoutualtana	V _I = 14.5 V to 27 V,	I _O = 5 mA to 350 mA		11.5	12	12.5	V
Output voltage	V = 14.5 V to 21 V,	10 = 3 IIIA to 330 IIIA	$T_J = 0$ °C to 125°C	11.4		12.6	V
Input voltage regulation	I _O = 200 mA	V _I = 14.5 V to 30 V			8	100	mV
Input voltage regulation	10 = 200 IIIA	V _I = 16 V to 30 V			2	50	IIIV
Pinnle rejection	V _I = 15 V to 25 V,	I _O = 100 mA,	$T_J = 0$ °C to 125°C	55			dB
Ripple rejection	f = 120 Hz	IO = 300 mA		55	80		uБ
Output voltage regulation	I _O = 5 mA to 500 mA				25	240	mV
Output voltage regulation	$I_O = 5 \text{ mA to } 200 \text{ mA}$				10	120	IIIV
Temperature coefficient of output voltage	I _O = 5 mA				-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				75		μV
Dropout voltage					2		V
Bias current					4.8	6	mA
Dies surrent change	V _I = 14.5 V to 30 V,	I _O = 200 mA,	$T_J = 0^{\circ}C$ to $125^{\circ}C$			0.8	A
Bias current change	$I_O = 5 \text{ mA to } 350 \text{ mA},$	T _J = 0°C to 125°C				0.5	mA
Short-circuit output current	V _I = 35 V				240		mA
Peak output current					0.7		Α

 $^{^{\}dagger}$ All characteristics are measured with a 0.33- μ F capacitor across the input and a 0.1- μ F capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

electrical characteristics at specified virtual junction temperature, V_I = 23 V, I_O = 350 mA, T_J = 25°C (unless otherwise noted)

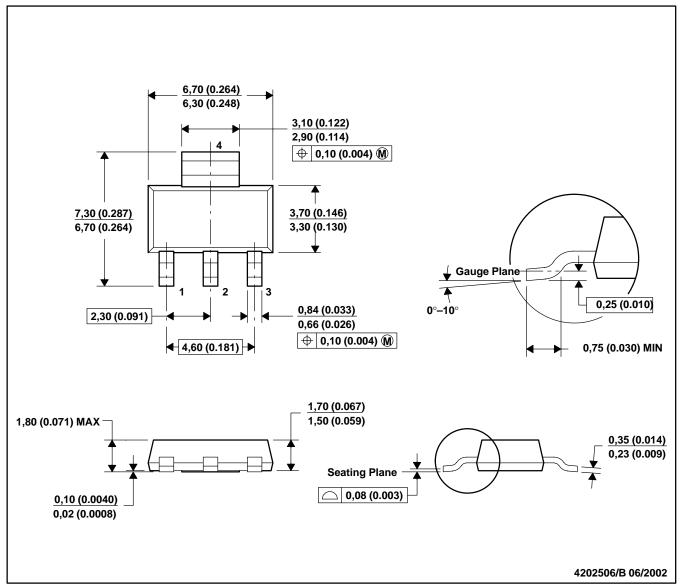
DADAMETED		TEST CONDITIONS!			78M150	C	UNIT
PARAMETER	TEST CONDITIONS†				TYP	MAX	UNIT
Outroit wells as	V ₁ = 17.5 V ₂ to 20 V	lo - 5 m \ to 350 m \		14.4	15	15.6	V
Output voltage	V _I = 17.5 V to 30 V,	$I_O = 5 \text{ mA to } 350 \text{ mA}$	$T_J = 0$ °C to 125°C	14.25		15.75	V
Input voltage regulation	I _O = 200 mA	V _I = 17.5 V to 30 V			10	100	mV
input voltage regulation	IO = 200 IIIA	V _I = 20 V to 30 V			3	50	IIIV
Ripple rejection	V _I = 18.5 V to 28.5 V,	$I_0 = 100 \text{ mA},$	$T_J = 0$ °C to 125°C	54			dB
Ripple rejection	f = 120 Hz	$I_0 = 300 \text{ mA}$		54	70		uБ
Output voltage regulation	$I_O = 5 \text{ mA to } 500 \text{ mA}$				25	300	mV
Output voltage regulation	I _O = 5 mA to 200 mA				10	150	IIIV
Temperature coefficient of output voltage	I _O = 5 mA,	$T_J = 0$ °C to 125°C			-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				90		μV
Dropout voltage					2		V
Bias current					4.8	6	mA
Diag gurrant abongs	V _I = 17.5 V to 30 V,	I _O = 200 mA,	$T_J = 0^{\circ}C$ to $125^{\circ}C$			0.8	mA
Bias current change	$I_0 = 5 \text{ mA to } 350 \text{ mA},$	T _J = 0°C to 125°C				0.5	IIIA
Short-circuit output current	V _I = 35 V				240		mA
Peak output current					0.7		Α

[†] All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.



DCY (R-PDSO-G4)

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters (inches).

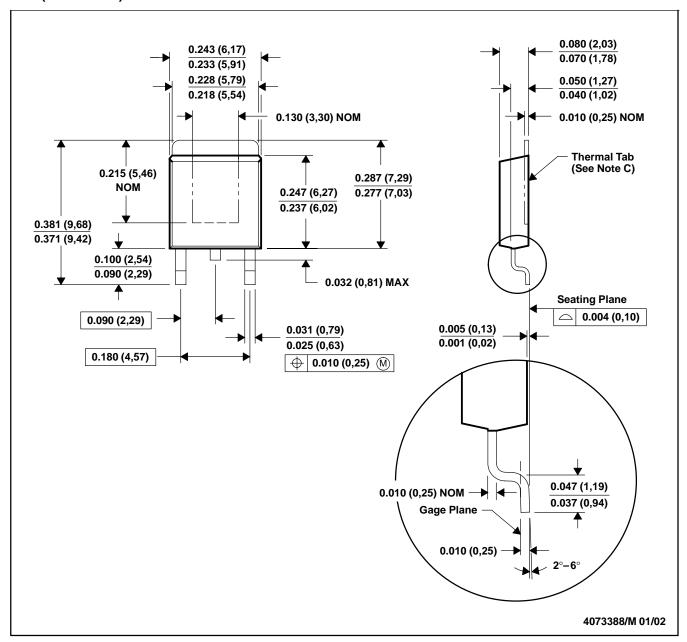
B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion.

D. Falls within JEDEC TO-261 Variation AA.

KTP (R-PSFM-G2)

PowerFLEX™ PLASTIC FLANGE-MOUNT PACKAGE



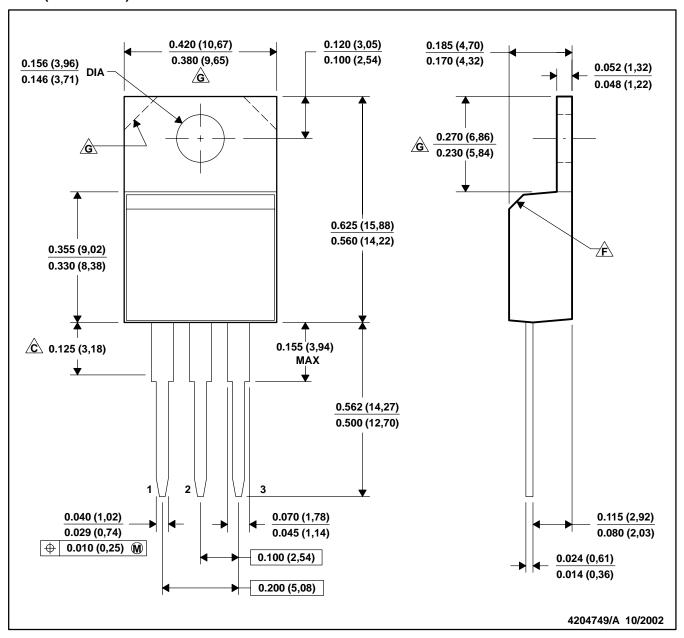
- NOTES: A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. The center lead is in electrical contact with the thermal tab.
 - D. Dimensions do not include mold protrusions, not to exceed 0.006 (0,15).
 - E. Falls within JEDEC TO-252 variation AC.

PowerFLEX is a trademark of Texas Instruments.



KCS (R-PSFM-T3)

PLASTIC FLANGE-MOUNT PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

This drawing is subject to change without notice.

Lead dimensions are not controlled within this area.

D. All lead dimensions apply before solder dip.

E. The center lead is in electrical contact with the mounting tab.

The chamfer is optional.

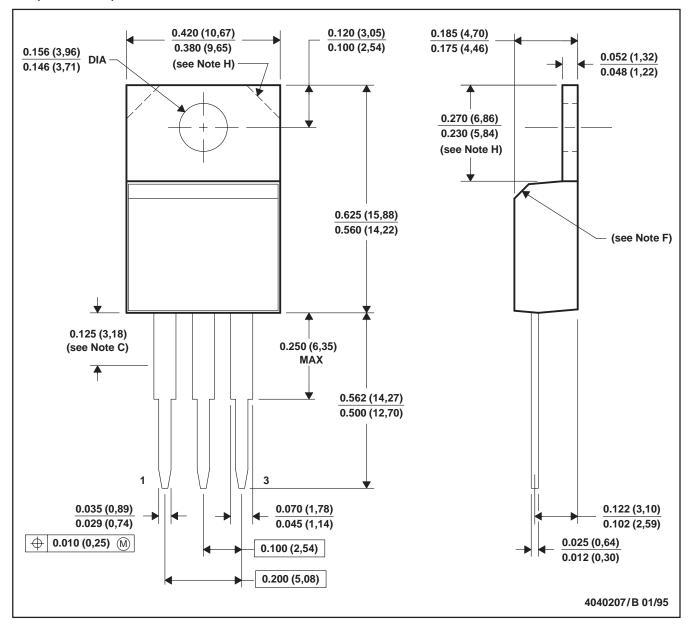
Tab contour optional within these dimensions.

H. Falls within JEDEC TO-220 variation AB.



KC (R-PSFM-T3)

PLASTIC FLANGE-MOUNT PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Lead dimensions are not controlled within this area.
- D. All lead dimensions apply before solder dip.
- E. The center lead is in electrical contact with the mounting tab.
- F. The chamfer is optional.
- G. Falls within JEDEC TO-220AB
- H. Tab contour optional within these dimensions



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third—party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Mailing Address:

Texas Instruments Post Office Box 655303 Dallas, Texas 75265

Copyright © 2002, Texas Instruments Incorporated